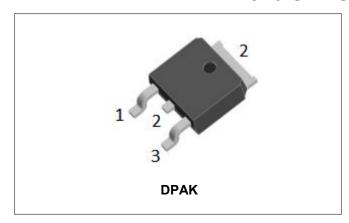






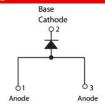
MBRD320 SCHOTTKY RECTIFIER



Features

- 150℃ T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- "-A" is an AEC-Q101 qualified device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Disk drives
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	20	V
Average Rectified Forward Current	l _{F (AV)}	50% duty cycle @Tc=125°C, rectangular wave form	3	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	75	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3A, Pulse, T _J = 25 °C @ 6A, Pulse, T _J = 25 °C	0.40 0.47	0.60 0.70	٧
	V _{F2}	@ 3A, Pulse, T _J = 125 °C @ 6A, Pulse, T _J = 125 °C	0.32 0.40	0.45 0.62	V
Reverse Current *	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.05	0.2	mA
	I _{R2}	$@V_R = \text{rated } V_{R}, T_J = 125 ^{\circ}\text{C}$	35	50	mA
Junction Capacitance	Ст	$@V_R = 5.0V, T_C = 25 °C$ $f_{SIG} = 1MHz$	230	300	pF

 $^{^{\}ast}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%



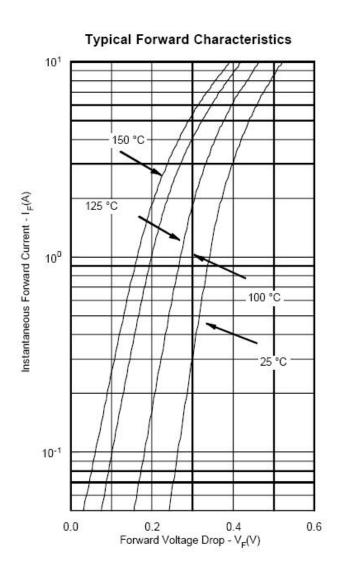




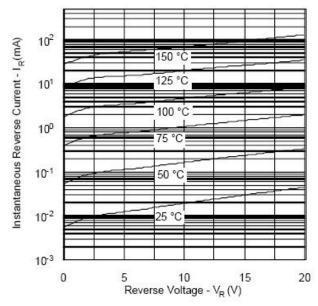
Thermal-Mechanical Specifications:

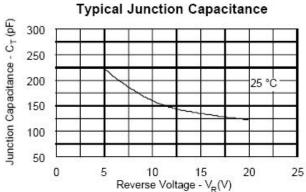
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R ₀ JC	-	6	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

Ratings and Characteristics Curves



Typical Reverse Characteristics





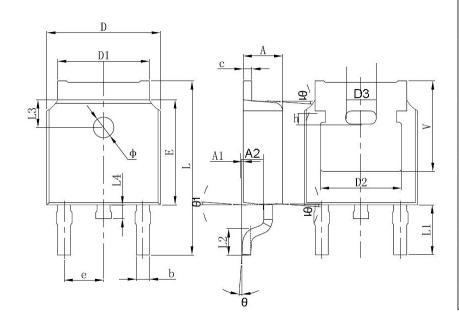
- China Germany Korea Singapore United States
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Mechanical Dimensions DPAK



SYMBOL	Millimeters		Inches		
STWBUL	Min.	Max.	Min.	Max.	
Α	2.20	2.40	0.087	0.094	
A1	0.00	0.127	0.000	0.005	
b	0.66	0.86	0.026	0.034	
С	0.46	0.60	0.018	0.024	
D	6.50	6.70	0.256	0.264	
D1	5.13	5.46	0.202	0.215	
D2	4.83 REF.		0.190 REF.		
Е	6.00	6.20	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.70	10.40	0.381	0.409	
L1	2.90 REF.		0.144 REF.		
L2	1.40	1.70	0.055	0.067	
L3	1.60 REF.		0.063 REF.		
L4	0.60	1.00	0.024	0.039	
Ф	1.10	1.30	0.043	0.051	
Θ	0°	8°	0°	8°	
h	0.00	0.30	0.000	0.012	
V	5.35 REF.		0.211	REF.	

Ordering Information

Device	Package	Shipping
MBRD320	DPAK (Pb-Free)	2500pcs / reel
MBRD320TR	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



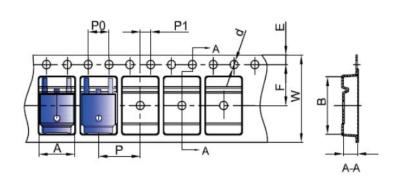
Where XXXXX is YYWWL

MBRD320 = Part Name SSG = SSG = Year = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape & Reel Specification DPAK



SYMBOL	Millimeters		
GTWIDOL	Min.	Max.	
Α	6.80	7.00	
В	10.40	10.60	
С	2.60	2.80	
d	Ф1.45	Ф1.65	
E	1.65	1.85	
F	7.40	7.60	
P0	3.90	4.10	
Р	7.90	8.10	
P1	1.90	2.10	
W	15.90	16.30	

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